

1N5817W~1N5819W

SCHOTTKY DIODES

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

DESCRIPTION

The 1N5817W~1N5819W are available in SOD-123FL package

ORDERING INFORMATION

Package Type	Part Number			
SOD-123FL	1N5817W			
	1N5818W			
	1N5819W			
Note	SPQ: 2,500pcs/Reel			
AiT provides all RoHS Compliant Products				

FEATURES

- Metal silicon junction, majority carrier conduction
- Guarding for overvoltage protection
- Low power loss, high efficiency
- High current capability
- low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Available in SOD-123FL package

PIN DESCRIPTION

1 2 Cathode Anode

REV1.0 - SEP 2021 RELEASED - -1-

ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter Parameter	Symbol	1N5817W	1N5818W	1N5819W	Unit		
Maximum Repetitive Peak Reverse	V_{RRM}	20	30	40	V		
Maximum RMS Voltage	V_{RMS}	14	21	28	V		
Maximum DC Blocking Voltage	V_{DC}	20	30	40	V		
Maximum Average Forward Rectified Current				А			
0.375" (9.5 mm) Lead Length at T_L :	I _{F(AV)}						
Peak Forward Surge Current, 8.3ms							
Sine-wave Superimposed On Rated	I _{FSM}		25		Α		
(JEDEC method) at T∟ = 70°C							
Maximum Instantaneous Forward	at I₅=1A	V_F	0.45	0.55	0.6		
Voltage	at I₅=3.1A	VF	0.75	0.875	0.9	V	
Maximum Instantaneous Reverse	T _A =25°C						
Current at Rated DC Reverse	T _A =23 C	I_R		mA			
Voltage	1A-100 C		10				
Typical Junction Capacitance		Сл	110			pF	
Typical Thermal Resistance		$R_{\theta JA}$	50			°C/W	
		Rejl					
Storage and Operating Junction Temperature		T T	EE . 149E			°C	
Range	T _J , T _{STG}		-55 ~+125		C		

REV1.0 - SEP 2021 RELEASED - -2 -



TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

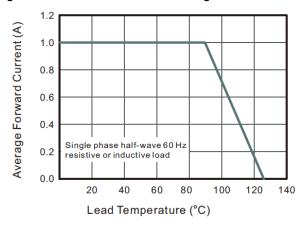


Figure. 3 Typical Forward Characteristic

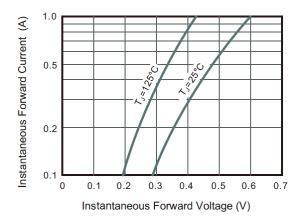


Figure. 5 Maximum Non-Repetitive Peak Forward Surge Current

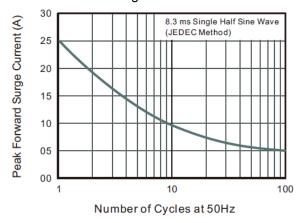


Figure. 2 Typical Reverse Characteristics

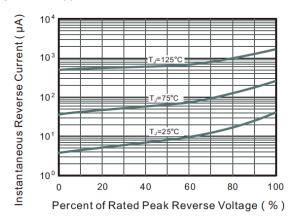


Figure. 4 Typical Junction Capacitance

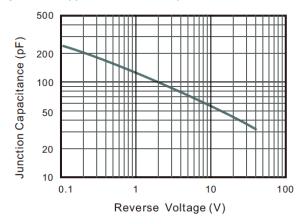
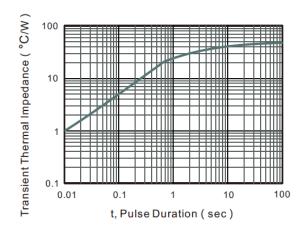


Figure. 6 Typical Transient Thermal Impedance

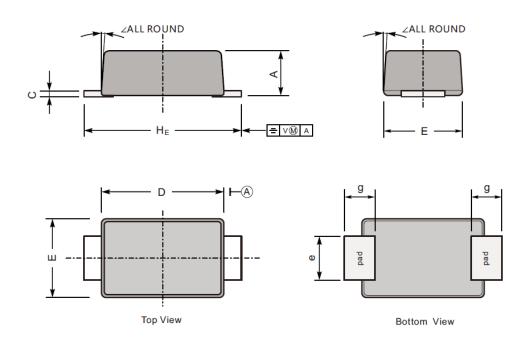


REV1.0 - SEP 2021 RELEASED -- 3 -

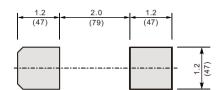
PACKAGE INFORMATION

Dimension in SOD-123FL (Unit: mm)

Plastic surface mounted package; 2 leads



The recommended mounting pad size



Unit: mm (mil)

UN	VIT	Α	С	D	E	е	g	HE	∠
mm	Max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	0.3
	Min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	Max	43	7.9	114	75	43	35	150	40
	Min	35	4.7	102	67	31	28	138	12

REV1.0 - SEP 2021 RELEASED - - 4 -



1N5817W~1N5819W

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REV1.0 - SEP 2021 RELEASED - - 5 -